General purpose transistor (isolated transistor and diode) **US5L10**

A 2SD2674 and a RB461F are housed independently in a TUMT5 package.

Applications

DC / DC converter Motor driver

● Features

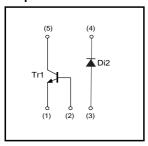
1) Tr : Low VcE(sat) Di : Low VF

2) Small package

●Structure

Silicon epitaxial planar transistor Schottky barrier diode

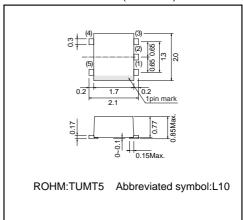
●Equivalent circuit



Packaging specification s

Туре	US5L10
Package	TUMT5
Marking	L10
Code	TR
Basic ordering unit(pieces)	3000

●External dimensions (Unit : mm)



Rev.A

●Absolute maximum ratings (Ta=25°C)

Tr1

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	15	V
Collector-emitter voltage	Vceo	12	V
Emitter-base voltage	Vево	6	V
Collector current	Ic	1.5	Α
	Іср	3	A *1
Power dissipation	Pc	0.9	W/ELEMENT *2
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-40 to +125	°C

Di2

Parameter	Symbol	Limits	Unit
Average rectified forward current	lF	700	mA
Forward current surge peak (60Hz, 1∞)	IFSM	3	Α
Reverse voltage (DC)	VR	20	V
Junction temperature	Tj	125	°C
Range of storage temperature	Tstg	-40 to +125	°C
Peak reverse voltage	VRM	25	V
Power dissipation	PD	0.5	W/ELEMENT *

^{*} Mounted on a 25mm×25mm×^t 0.8mm ceramic substrate

Tr1& Di2

Parameter	Symbol	Limits	Unit
Total power dissipation	Pp	0.4	W/TOTAL *1
	I D	1.0	W/TOTAL *2

●Electrical characteristics (Ta=25°C)

Tr1

Symbol	Min.	Тур.	Max.	Unit	Conditions
ВУсво	15	-	_	V	Ic=10μA
BVceo	12	_	_	V	Ic=1mA
ВУево	6	_	_	V	Iε=10μA
Ісво	_	_	100	nA	VcB=15V
ІЕВО	_	_	100	nA	V _{EB} =6V
VCE(sat)	_	85	200	mV	Ic/I _B =500mA/25mA
hfe	270	_	680	-	Vce/Ic=2V/200mA *
f⊤	_	400	_	MHz	Vce=2V, Ie=-200mA, f=100MHz *
Cob	_	12	_	рF	Vcb=10V, Ie=0A, f=1MHz
	BVCBO BVCEO BVEBO ICBO ICBO VCE(sat) hFE	BVCBO 15 BVCBO 12 BVEBO 6 ICBO - IEBO - VCE(sat) - hfe 270 ft -	BVCBO 15 - BVCEO 12 - BVEBO 6 - ICBO IEBO VCE(sat) - 85 hfe 270 - fr - 400	BVCBO 15 BVCEO 12 BVEBO 6 ICBO 100 IEBO 100 VCE(sat) - 85 200 hfe 270 - 680 ft - 400 -	BVcBO 15 - V BVcEO 12 - V BVEBO 6 - V ICBO - 100 nA IEBO - 100 nA VCE(sat) - 85 200 mV hfe 270 - 680 - ft - 400 - MHz

^{*} Pulsed

Di2

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	_	450	490	mV	I _F =700mA
Reverse current	lr	_	-	200	μΑ	V _R =20V
Reverse recovery time	trr	_	9	_	ns	IF=IR=100mA, Irr=0.1IR



^{*1} Single pulse, Pw=1ms. *2 Mounted on a 25mm×25mm×^t0.8mm ceramic substrate

^{*1} Each terminal mounted on a recommended land *2 Mounted on a 25mm×25mm×10.8mm ceramic substrate

•Electrical characteristic curves

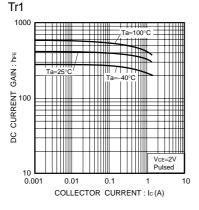


Fig.1 DC current gain vs. collector current

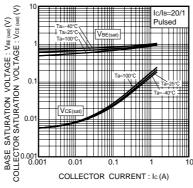


Fig.2 Collector-emitter saturation voltage base-emitter saturation voltage vs. collector current

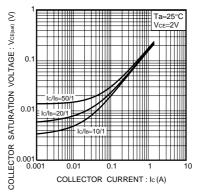


Fig.3 Collector-emitter saturation voltage vs. collector current

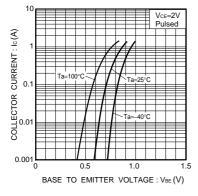


Fig.4 Grounded emitter propagation characteristics

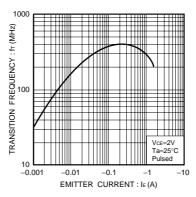


Fig.5 Gain bandwidth product vs. emitter current

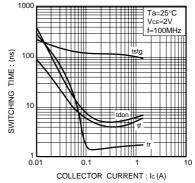


Fig.6 Switching time

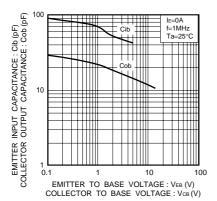


Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

Transistors

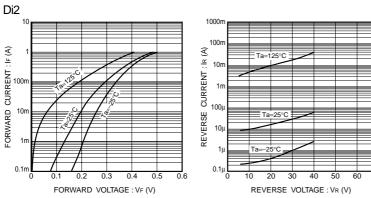


Fig.9 Forward characteristics

Fig.10 Reverse characteristics

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